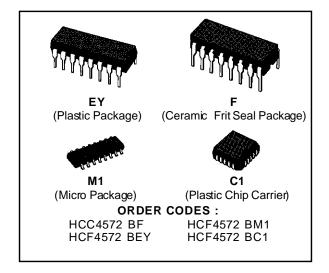


HCC4572B HCF4572B

HEX GATE

PRODUCT PREVIEW

- VERY LOW QUIESCENT CURRENT
- HIGH NOISE IMMUNITY
- SINGLE SUPPLY OPERATION
- SUPPLY VOLTAGE RANGE 3V TO 18V
- HIGH INPUT IMPEDANCE
- PIN LAYOUT OPTIMISED FOR MAXIMUM FLEXIBILITY



PIN CONNECTION (top view) J≃Ā V_{DD} Α Н K=B G В P=G·H F L=C+D C N=F Ε D M=E V_{SS}

DESCRIPTION

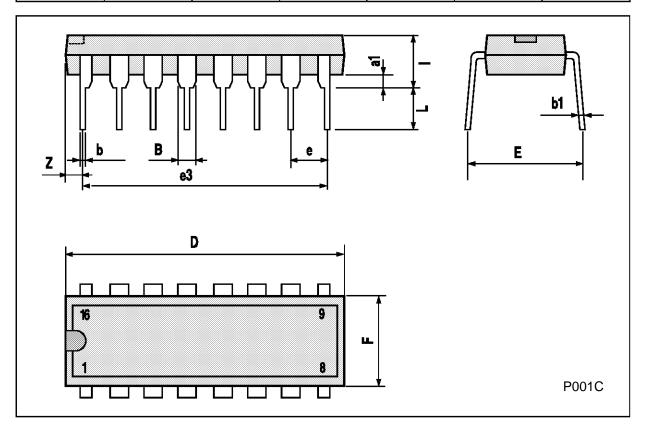
The HCC4572B and HCF4572B are a monolithic integrated circuits, available in 16-lead dual-in-line plastic and ceramic packages and plastic micro packages.

The HCC4572B and HCF4572B are hex functional gates containing one NOR gate, one NAND gate and four inverters. These devices are intended for application where low power dissipation and/or high noise immunity is required.

September 1990

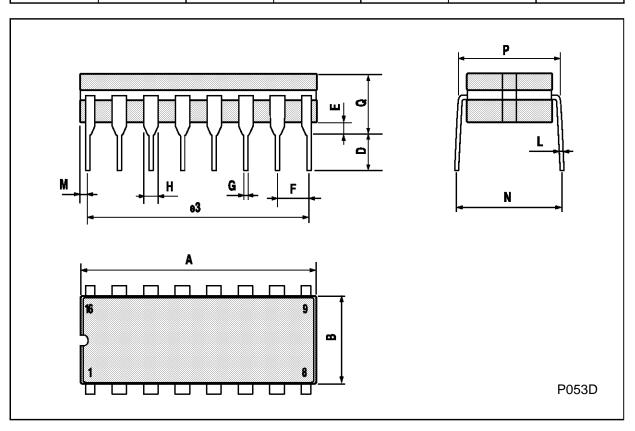
Plastic DIP16 (0.25) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
В	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
е		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



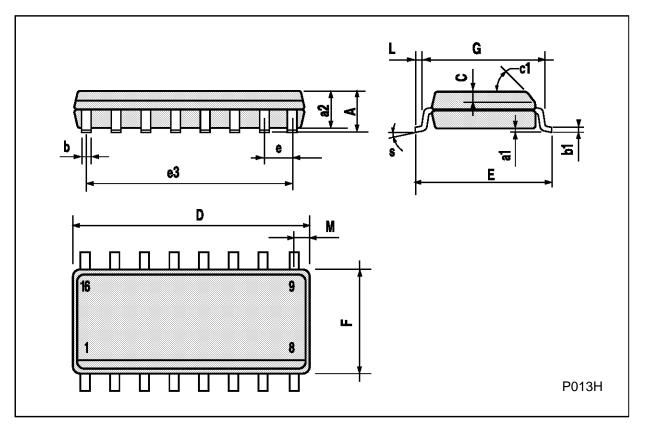
Ceramic DIP16/1 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α			20			0.787
В			7			0.276
D		3.3			0.130	
E	0.38			0.015		
e3		17.78			0.700	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
Н	1.17		1.52	0.046		0.060
L	0.22		0.31	0.009		0.012
M	0.51		1.27	0.020		0.050
N			10.3			0.406
Р	7.8		8.05	0.307		0.317
Q			5.08			0.200



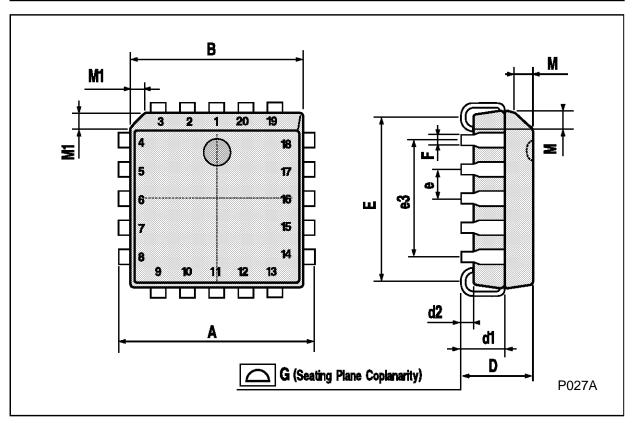
SO16 (Narrow) MECHANICAL DATA

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			1.75			0.068	
a1	0.1		0.2	0.004		0.007	
a2			1.65			0.064	
b	0.35		0.46	0.013		0.018	
b1	0.19		0.25	0.007		0.010	
С		0.5			0.019		
c1	45° (typ.)						
D	9.8		10	0.385		0.393	
Е	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		8.89			0.350		
F	3.8		4.0	0.149		0.157	
G	4.6		5.3	0.181		0.208	
L	0.5		1.27	0.019		0.050	
М			0.62			0.024	
S	8° (max.)						



PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	9.78		10.03	0.385		0.395
В	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
е		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
М		1.27			0.050	
M1		1.14			0.045	



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